AVG Semiconductors

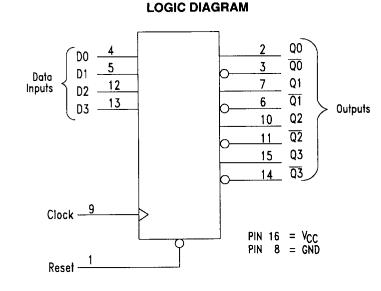
Technical Data

Available Q3, 1995

Quad D Flip-Flop with Master Reset

This device consists of four D flip-flops with common Reset and Clock inputs, and separate D inputs. Reset (active-low) is asynchronous and occurs when a low level is applied to the Reset input. Information at D inputs is transferred to the corresponding Q outputs on the next positive-going edge of the Clock input.

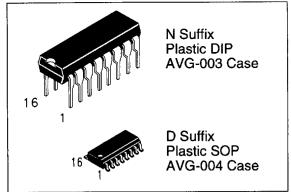
- Advanced very high speed CMOS
- Outputs source/sink 24 mA
- Transmission line driving 50 ohms
- ACT has TTL compatible inputs
- Operation from 2 to 6 volts guaranteed
- DC & AC Parameters guaranteed over –40 to +85°C



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DV74AC175 DV74ACT175

DDi™



PIN ASSIGNMENT

Reset		1 •	16	þ	Vcc
QO	Ц	2	15	þ	Q3
QO	С	4	14		Q3
DO		5	13	þ	D3
D1	d	3	12	þ	D2
<u>Q1</u>		6	11	þ	<u>Q2</u>
Q1		7	10		Q2
GND		8	9	þ	Clock

TRUTH TABLE

Inputs			Output			
Reset	СР	D	Qn	Qn		
L	X	х	L	н		
Н		н	Н	L		
Н	↑	L	L	H		
н	L	Х	Qn	H Qn		

H=HIGHVoltageLevel,L=LOWVoltageLevel X=EitherLoworHighLogicLevel ^=LOW to HIGH transition of Clock

ABSOLUTE MAXIMUM RATINGS

Maximum ratings are those values beyond which damage to the device may occur.

Symbol	Parameter	AC175, ACT175	Unit
Vcc	DC Supply Voltage (Referenced to GND)	– 0.5 to +7.0	V
Vin	DC Input Voltage (Referenced to GND)	- 0.5 to V _{CC} +0.5	V
Vout	DC Output Voltage (Referenced to GND)	- 0.5 to V _{CC} +0.5	V
lin	DC Input Current, per Pin	±20	mA
Іоџт	DC Output Sink/Source Current, per Pin	± 50	mA
lcc	DC V _{CC} or GND Current per Output Pin	± 50	mA

Downloaded DV74ACT175, DV74ACT175hts distributor

GUARANTEED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
Vcc	Supply Voltage	'AC	2.0	5.0	6.0	V
		'ACT	4.5	5.0	5.5	1
VIN, VOUT	DC Input Voltage, Output Voltage, (Re	f. to GND)	0		Vcc	V
t _r , t _f	Input Rise and Fall Time (Note 1) AC Devices	Vcc @ 3.0 V			150	ns/V
		Vcc @ 4.5 V			40	ns/V
		Vcc @ 5.5 V			25	ns/V
tr, tf	Input Rise and Fall Time (Note 2)	Vcc @ 4.5 V			10	ns/V
	ACT Devices	Vcc @ 5.5 V			8.0	ns/V
TA	Operating Ambient Temperature Range)	-40		85	°C
CPD	Power Dissipation Capacitance	Vcc= 5.0 V		45	-	pF
CiN	Input Capacitance V _{CC} = 5.0 V	V _{CC} = 5.0 V		4.5		pF

1. VIN from 30% to 70% VCC

2. $V_{\rm IN}$ from 0.8 to 2.0 V



DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Vcc		AC17	5	Unit
			(V)			$T_{A} = -40$ to +85°C	
				Тур	Guaran	teed Limits	
VIH	Minimum High Level Input Voltage	Vout = 0.1V or V _{CC} - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V
VIL	Maximum Low Level Input Voltage	V _{OUT} = 0.1V or V _{CC} - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V
Vон	Minimum High Level Output Voltage	Ιουτ = -50 μΑ	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V
		V _{IN} = V _{IL} or V _{IH} -12mA I _{OH} -24mA -24 mA	3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	v
Vol	MaximumLow Level Output Voltage	Ιουτ= 50 μΑ	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V
		VIN = VIL or VIH 12mA IOH 24mA 24 mA	3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	v
lın	Maximum Input Leakage Current	VI=V _{CC} , GND	5.5		±0.1	±1.0	μ A
Icc	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5		8.0	80	μA

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AC CHARACTERISTICS

Symbol	Parameter	Vcc		AC175				
Cy.ii.zei	(C _L = 50 pF)	±10% (V)	T _A = -	⊧25°C	T _A = - 40°C to +85°C			
			Min	Max	Min	Max		
fmax	Maximum Clock Frequency	3.3 5.0	149 187		139 187		MHz	
t PLH	Propagation Delay CP to Q _n	3.3 5.0	2.0 1.5	12 9.0	2.0 1.0	13.5 9.5	ns	
t PHL		3.3 5.0	2.5 1.5	13 9.5	2.0 1.5	14.5 10.5		
tplh	Propagation Delay Reset to Q _n	3.3 5.0	3.0 2.0	12.5 9.0	2.5 1.5	13.5 10.0	ns	
t PHL		3.3 5.0	3.0 2.0	11.0 8.5	2.5 1.5	12.5 9.0		

AC OPERATING REQUIREMENTS

Symbol	Parameter	Vcc		Unit		
-,	(С _L = 50 рF)	10% (V)(ς)	T _A = +	-25°C	T _A = - 40°C to +85°C	
			Тур	Guara	anteed Minimum	
ts	Setup Time, HIGH or LOW, Dn to CP	3.3 5.0		4.5 3.0	4.5 3.0	ns
t _h	Hold Time, HIGH or LOW, Dn to CP	3.3 5.0		1.0 1.0	1.0 1.0	ns
tw	MR Pulse Width, LOW	3.3 5.0		4.5 3.5	4.5 3.5	ns
tw	CP Pulse Width	3.3 5.0		4.5 3.5	5.0 3.5	ns
t _{rec}	Recovery Time, MR to CP	3.3 5.0		0 0	0 0	ns

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Vcc	ACT175		Unit
			(V)	TA = +25°C	TA = -40 to +85°C	
				Guarante	ed Limits	
ViH	Minimum High Level Input Voltage	V _{OUT} = 0.1V or V _{CC} - 0.1 V	4.5 5.5	2.0 2.0	2.0 2.0	۷
VIL	Maximum Low Level Input Voltage	V _{OUT} = 0.1V or V _{CC} - 0.1 V	4.5 5.5	0.8 0.8	0.8 0.8	V
Vон	Minimum High Level Output Voltage	I _{OUT} = -50 μA	4.5 5.5	4.4 5.4	4.4 5.4	V
		V _{IN} = V _{IL} or V _{IH} I _{OH} —24mA —24 mA	4.5 5.5	3.86 4.86	3.76 4.76	v
Vol	Maximum Low Level Output Voltage	Ι _{ΟUT} = 50 μΑ	4.5 5.5	0.1 0.1	0.1 0.1	V
		$V_{IN} = V_{IL} \text{ or } V_{IH}$ IOL 24mA 24 mA	4.5 5.5	0.36 0.36	0.44 0.44	V
lin	Maximum Input Leakage Current	VI=VCC, GND	5.5	±0.1	±1.0	μA

Symbol	Parameter	Conditions	Vcc	ACT175		Unit
			(V)	TA = +25°C	TA = -40 to +85°C	
∆Ісст	Additional Max Icc/Input	VI=VCC - 2.1 V	5.5	Guarante	ed Limits	mA
lcc	Maximum Quiescent Supply Current	VIN = VCC or GND	5.5	8.0	80	μΑ

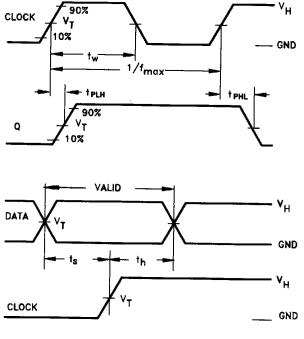
AC CHARACTERISTICS

Symbol	Parameter	Vcc		Unit			
	(C _L = 50 pF)	±10% (V)	T _A = +25 ^o C		$T_{A} = -40^{\circ}C \text{ to}$ $+85^{\circ}C$]
			Min	Max	Min	Max	7.
fmax	Maximum Clock Frequency	5.0	175		145		MHz
t PLH	Propagation Delay, Clock to Qn	5.0	2.0	10.0	1.5	11.0	ns
t PHL	Propagation Delay, Clock to Qn	5.0	2.0	11.0	1.5	12.0	ns
t PHL	Propagation Delay, Master Reset to Qn	5.0	2.0	9.5	1.5	10.5	ns

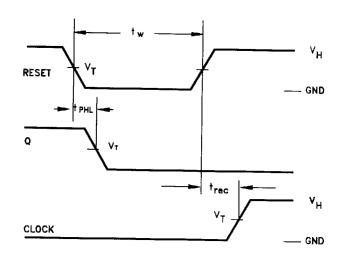
AC OPERATING REQUIREMENTS

Symbol	Parameter	Vcc	AC	CT175	Unit
	(C∟ = 50 pF)	±10% (V)	T _A = +25°C	$T_A = -40^{\circ}C \text{ to}$ $+85^{\circ}C$	-
			Guarante	ed Minimum	-
ts	Setup Time, HIGH or LOW, Dn to CP (H) (L)	5.0	2.0 2.5	2.0 2.5	ns
t _h	Hold Time, HIGH or LOW, Dn to CP	5.0	1.0	1.0	ns
tw	MR Pulse Width, LOW	5.0	3.0	4.0	ns
tw	CP Pulse Width	5.0	3.0	3.5	ns
t _{rec}	Recovery Time, MR to CP	5.0	0	0	ns

SWITCHING WAVEFORMS



Input and output threshold voltage: $V_T = 50\%$ Vcc for AC; 1.5V for ACT $V_H = V_{CC}$ for AC, 3V for ACT



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